NSN 5962-01-463-5332



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-463-5332 **Body Length:** 1.280 inches **Body Width:** 0.200 inches **Body Height:** 0.310 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** B- (fmf) **Features Provided:** Low power **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Criticality Code Justification:** Feat **Case Outline Source And Designator:** D-9 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Microcircuit, digital, cmos, 256k x1 static ram, low power **Voltage Rating And Type Per Characteristic:** -0.5 volts input and 7.0 volts input **Time Rating Per Chacteristic:** 45.00 nanoseconds access **Memory Device Type:**

Ram

Special Features:

Hardness critical item

Nuclear Hardness Critical Feature:

Hardened

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

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Memory Microcircuit - Page 2 of 2



Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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